## NSN 5962-01-306-4480

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View Online at https://aerobasegroup.com/nsn/5962-01-306-4480

Overall Length:
1.060 inches
Overall Height:
0.400 inches
Overall Width:
0.320 inches
Body Length:
1.060 inches
Body Width:
0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and electrostatic sensitive and monolithic and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-8 mil-m-38510
Current Rating Per Characteristic:
70.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder

**Voltage Rating And Type Per Characteristic:** 

7.0 volts power source

**Time Rating Per Chacteristic:** 

30.00 nanoseconds input

**Memory Device Type:** 

Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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20 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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